## NSN 5961-00-267-5417

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View Online at https://aerobasegroup.com/nsn/5961-00-267-5417 **Inclosure Material:** Plastic **Overall Length:** 0.450 inches **Overall Diameter:** 0.330 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Base **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 450.0 breakdown voltage, collector-to-base, emitter open and 5.0 breakdown voltage, emitter-to-base, collector open and 350.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 300.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 15.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 165.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0